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Substitute for form 1449A/PTO INFORMATION DISCLOSURE STATEMENT BY APPLICANT <i>(Use as many sheets as necessary)</i>		<i>Complete if Known</i>	
		Application Number	Unknown
		Filing Date	Even Date Herewith
		First Named Inventor	Moradi, Behnam
		Group Art Unit	Unknown
		Examiner Name	Ramsey, Kenneth
Sheet 1 of 2		Attorney Docket No: 303.591US2	

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EXAMINER Plenn Zimmerman DATE CONSIDERED 6/2/04

Substitute Disclosure Statement Form (PTO-1449)
 EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP 609. Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant. 1 Applicant's unique citation designation number (optional) 2 Applicant is to place a check mark here if English language Translation is attached

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		Examiner Name	Ramsey, Kenneth
Sheet 2 of 2		Attorney Docket No: 303.591US2	

OTHER DOCUMENTS -- NON PATENT LITERATURE DOCUMENTS		
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